

## AAP Gen 7 (TO-240AA) Power Modules Schottky Rectifier, 200 A



AAP Gen 7 (TO-240AA)


### PRIMARY CHARACTERISTICS

$I_{F(AV)}$	200 A
$V_R$	45 V
Package	AAP Gen 7 (TO-240AA)
Circuit configuration	Two diodes doubler circuit

### MECHANICAL DESCRIPTION

The AAP Gen 7, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

### FEATURES

- 150 °C  $T_J$  operation
- Low forward voltage drop
- High frequency operation
- Low thermal resistance
- UL approved file E78996 
- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



**RoHS**  
COMPLIANT

### BENEFITS

- Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- Easy mounting on heatsink

### ELECTRICAL DESCRIPTION / APPLICATIONS

The VS-VSKDS400/045 Schottky rectifier doubler has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

### MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
$I_{F(AV)}$	Rectangular waveform	200	A
$V_{RRM}$		45	V
$I_{FSM}$	$t_p = 5 \mu s$ sine	29 000	A
$V_F$	100 A <sub>pk</sub> , $T_J = 125$ °C	0.5	V
$T_J$	Range	-55 to +150	°C

### VOLTAGE RATINGS

PARAMETER	SYMBOL	VS-VSKDS400/045	UNITS
Maximum DC reverse voltage	$V_R$	45	V
Maximum working peak reverse voltage	$V_{RWM}$		

**ABSOLUTE MAXIMUM RATINGS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	50 % duty cycle at $T_C = 91\text{ }^{\circ}\text{C}$ , rectangular waveform	200	A
Maximum peak one cycle non-repetitive surge current	$I_{FSM}$	5 $\mu\text{s}$ sine or 3 $\mu\text{s}$ rect. pulse	29 000	
		10 ms sine or 6 ms rect. pulse	3400	
Non-repetitive avalanche energy	$E_{AS}$	$T_J = 25\text{ }^{\circ}\text{C}$ , $I_{AS} = 19\text{ A}$ , $L = 1\text{ mH}$	180	mJ
Repetitive avalanche current	$I_{AR}$	Current decaying linearly to zero in 1 $\mu\text{s}$ Frequency limited by $T_J$ maximum $V_A = 1.5 \times V_R$ typical	40	A

**ELECTRICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum forward voltage drop	$V_{FM}$	200 A	0.67	V
		400 A	0.92	
		200 A	0.73	
		400 A	1.14	
Maximum reverse leakage current	$I_{RM}$	$T_J = 25\text{ }^{\circ}\text{C}$	20	mA
		$T_J = 125\text{ }^{\circ}\text{C}$	1.2	A
Maximum junction capacitance	$C_T$	$V_R = 5\text{ V}_{DC}$ (test signal range 100 kHz to 1 MHz), $25\text{ }^{\circ}\text{C}$	10 300	pF
Typical series inductance	$L_S$	Measured lead to lead 5 mm from package body	5.0	nH
Maximum voltage rate of change	$dV/dt$	Rated $V_R$	10 000	V/ $\mu\text{s}$
Maximum RMS insulation voltage	$V_{INS}$	50 Hz	3000 (1 min) 3600 (1 s)	V

**THERMAL - MECHANICAL SPECIFICATIONS**

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-55 to +150	°C
Maximum thermal resistance, junction to case per leg	R <sub>thJC</sub>	DC operation	0.26	°C/W
Typical thermal resistance, case to heatsink per module	R <sub>thCS</sub>		0.1	
Approximate weight			75	g
			2.7	oz.
Mounting torque ± 10 %	to heatsink	A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the spread of the compound.	4	Nm
	busbar		3	
Case style		JEDEC®	TO-240AA compatible	

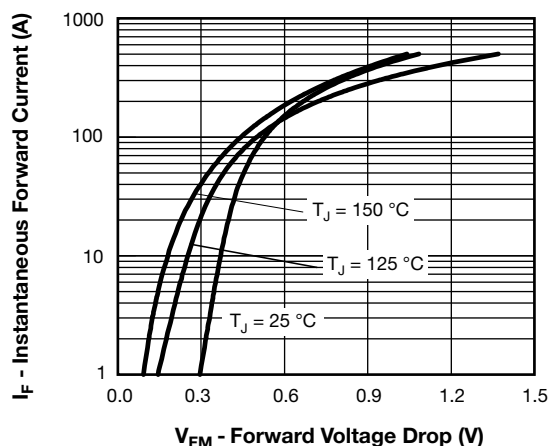


Fig. 1 - Maximum Forward Voltage Drop Characteristics

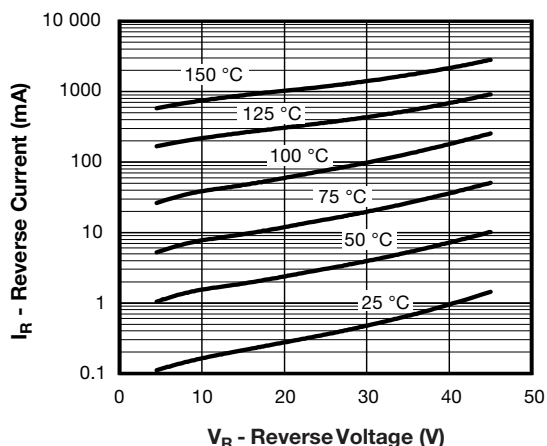


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

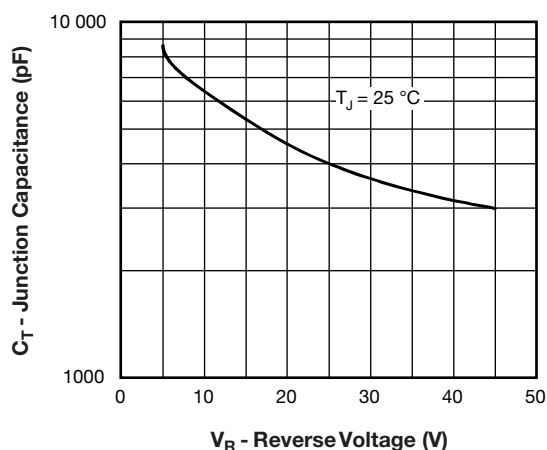
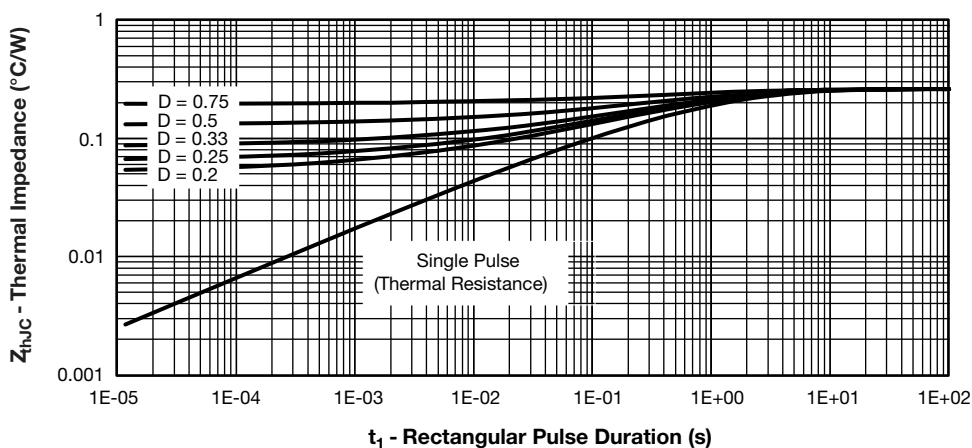


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage


Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics

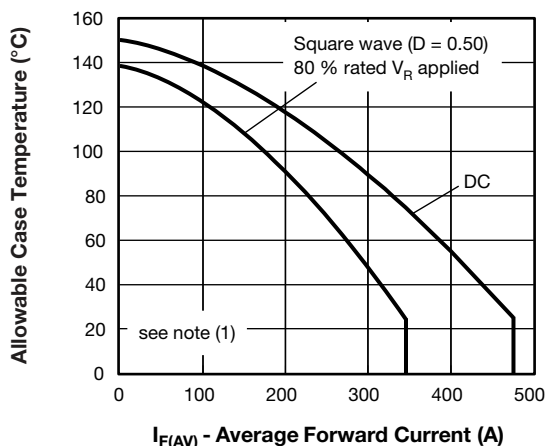


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

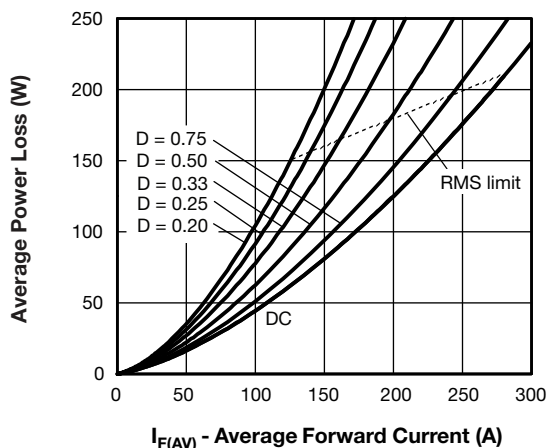


Fig. 6 - Forward Power Loss Characteristics

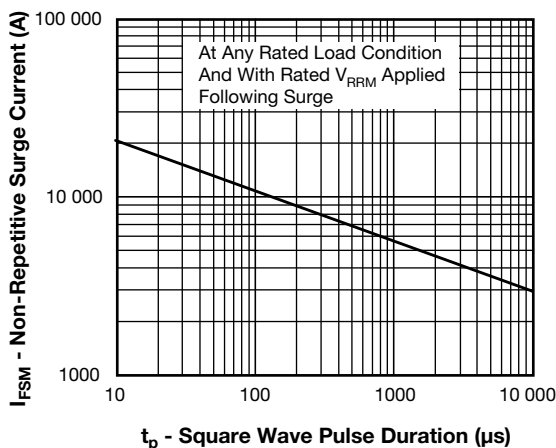


Fig. 7 - Maximum Non-Repetitive Surge Current

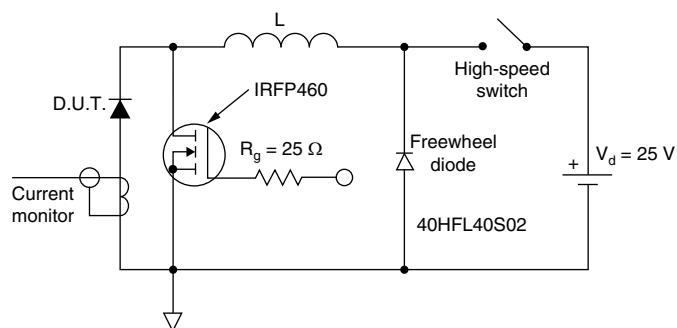


Fig. 8 - Unclamped Inductive Test Circuit

#### Note

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 6);  
 $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1} = 80\%$  rated  $V_R$

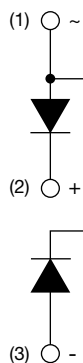


## ORDERING INFORMATION TABLE

Device code	VS-VS	KD	S	40	0	/	045
	1	2	3	4	5		6

- 1** - VS-VS = Vishay Semiconductors product
- 2** - Circuit configuration:  
KD = ADD-A-PAK - 2 diodes doubler circuit
- 3** - S = Schottky diode
- 4** - Average rating (x 10)
- 5** - Product silicon identification
- 6** - Voltage rating (045 = 45 V)

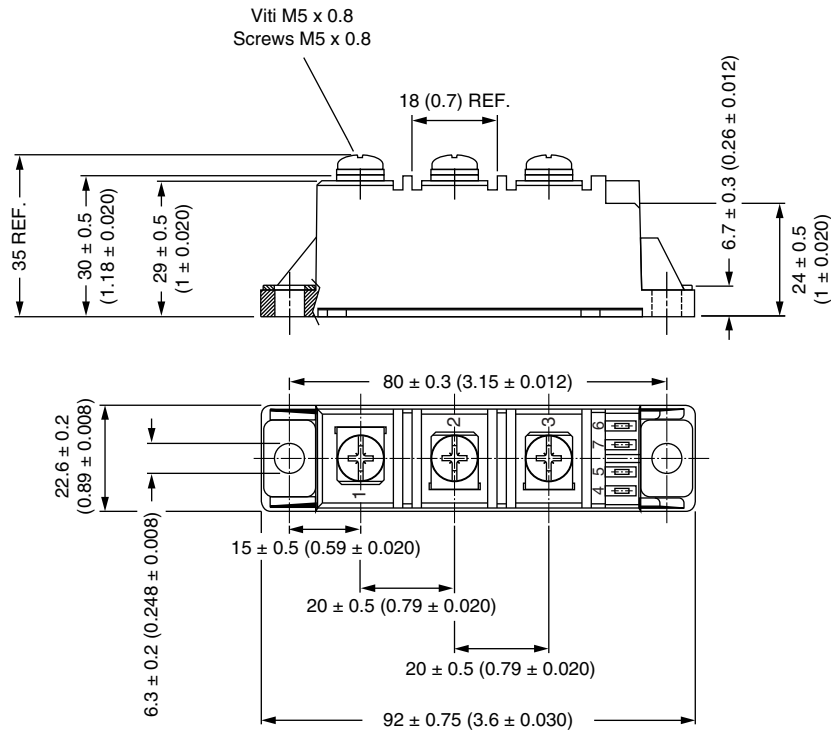
## CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS	
Dimensions	<a href="http://www.vishay.com/doc?95369">www.vishay.com/doc?95369</a>

## ADD-A-PAK Generation VII - Diode

**DIMENSIONS** in millimeters (inches)





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